Exceptionally Low Forward Voltage Trench-based Schottky Rectifier

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These are Pb-Free and Halide-Free Devices

Typical Applications

- Switching Power Supplies including Wireless, Smartphone and Notebook Adapters
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting SurfaceTemperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements



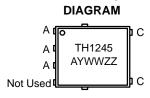
ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 12 AMPERES 45 VOLTS







MARKING

TH1245 = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

| Device | Package | Shipping† |
|---------------|----------------------|-----------------------|
| NTS1245MFST1G | SO-8 FL (Pb-Free) | 1500 / Tape & Reel |
| NTS1245MFST3G | SO-8 FL (Pb-Free) | 5000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 45 | V |
| Average Rectified Forward Current (Rated V _R , T _C = 142°C) | I _{F(AV)} | 12 | А |
| Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz, T _C = 140°C) | I _{FRM} | 24 | А |
| Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) | I _{FSM} | 210 | А |
| Storage Temperature Range | T _{stg} | -65 to +150 | °C |
| Operating Junction Temperature | TJ | -55 to +150 | °C |
| Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive) | E _{AS} | 100 | mJ |
| ESD Rating (Human Body Model) | | 3B | |
| ESD Rating (Machine Model) | | M4 | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Тур | Max | Unit |
|--|-----------------|-----|-----|------|
| Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm² 1 oz. copper bond pad, on a FR4 board) | $R_{\theta JC}$ | 1.8 | ı | °C/W |

ELECTRICAL CHARACTERISTICS

| Instantaneous Forward Voltage (Note 1) ($i_F = 6.0 \text{ Amps}, T_J = 25^{\circ}\text{C}$) ($i_F = 12 \text{ Amps}, T_J = 25^{\circ}\text{C}$) | V _F | 0.42 0.48 | - 0.57 | ٧ |
|---|----------------|--------------|-----------|----------|
| $(i_F = 6.0 \text{ Amps}, T_J = 125^{\circ}\text{C})$ $(i_F = 12 \text{ Amps}, T_J = 125^{\circ}\text{C})$ | | 0.32 0.40 | – 0.51 | |
| Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$) | i _R | - 15 | 120 45 | μA mA |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

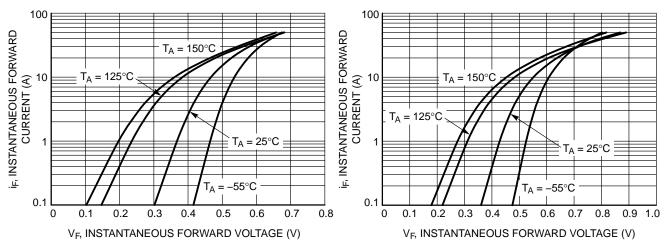


Figure 1. Typical Instantaneous Forward Characteristics

Figure 2. Maximum Instantaneous Forward Characteristics

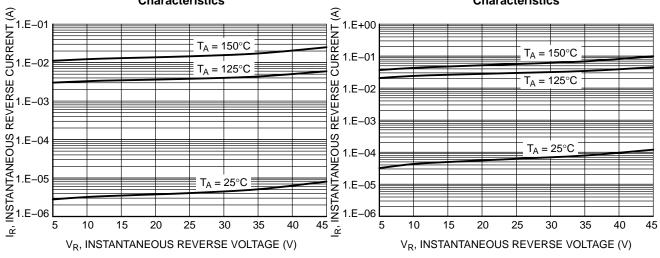


Figure 3. Typical Reverse Characteristics

Figure 4. Maximum Reverse Characteristics

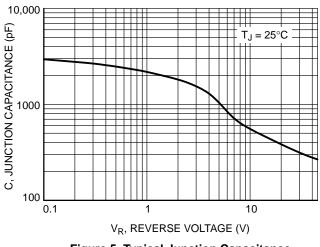


Figure 5. Typical Junction Capacitance

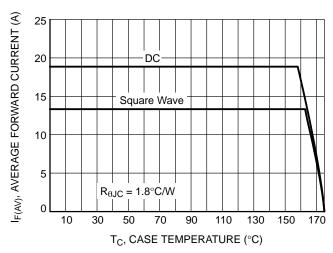


Figure 6. Current Derating per Device

TYPICAL CHARACTERISTICS

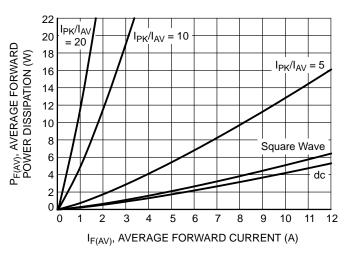


Figure 7. Forward Power Dissipation

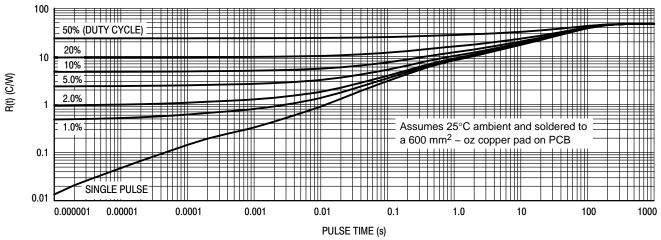


Figure 8. Typical Thermal Characteristics

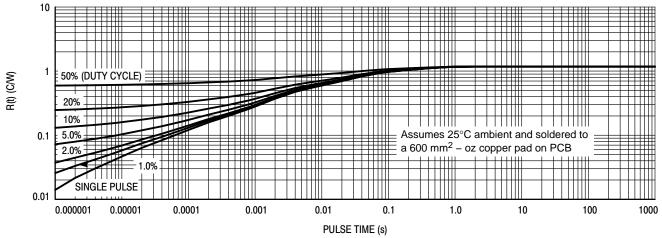


Figure 9. Typical Transient Thermal Response Characteristics, Junction-to-Case





DFN5 5x6, 1.27P (SO-8FL) CASE 488AA **ISSUE N**

DATE 25 JUN 2018

NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION D1 AND E1 DO NOT INCLUDE
- MOLD FLASH PROTRUSIONS OR GATE BURRS

| | MILLIMETERS | | | |
|-----|-------------|-------|------|--|
| DIM | MIN | NOM | MAX | |
| Α | 0.90 | 1.00 | 1.10 | |
| A1 | 0.00 | | 0.05 | |
| b | 0.33 | 0.41 | 0.51 | |
| С | 0.23 | 0.28 | 0.33 | |
| D | 5.00 | 5.15 | 5.30 | |
| D1 | 4.70 | 4.90 | 5.10 | |
| D2 | 3.80 | 4.00 | 4.20 | |
| E | 6.00 | 6.15 | 6.30 | |
| E1 | 5.70 | 5.90 | 6.10 | |
| E2 | 3.45 | 3.65 | 3.85 | |
| е | 1.27 BSC | | | |
| G | 0.51 | 0.575 | 0.71 | |
| K | 1.20 | 1.35 | 1.50 | |
| L | 0.51 | 0.575 | 0.71 | |
| L1 | 0.125 REF | | | |
| М | 3.00 | 3.40 | 3.80 | |
| θ | 0 ° | | 12 ° | |

GENERIC MARKING DIAGRAM*

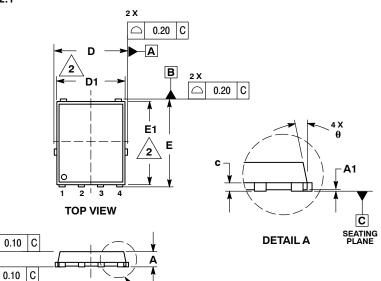


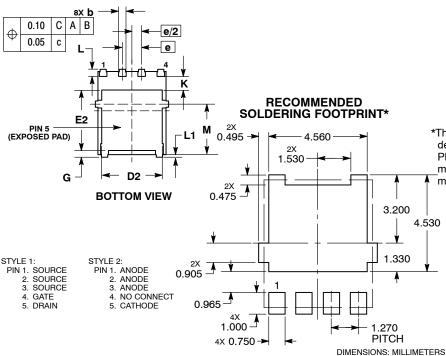
XXXXXX = Specific Device Code

= Assembly Location Α

Υ = Year W = Work Week ZZ = Lot Traceability

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.





DETAIL A

SIDE VIEW

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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|---|------------------|--------------------------|--|-------------|
| ſ | DESCRIPTION: | DFN5 5x6, 1.27P (SO-8FL) | | PAGE 1 OF 1 |

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